## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

ATTY.'S DOCKET: 98 P7501 US 01

In re the application of: Ramachandran et al.

Group Art: 1746

Serial No.: 09/204,706

Examiner: A. Olsen

Filing Date: December 3, 1998

Title: REMOVAL OF POST-RIE POLYMER)

ON Al/Cu METAL LINE

RECEIVED

AMENDMENT UNDER 37 C.F.R. §1.115

Honorable Commissioner of Patents and Trademarks Washington, D.C. 20231

Sir:

In reply to the Office Action mailed December 18, 2001, which rejected the claims in the above-identified patent application, applicants respectfully request reconsideration, based upon the amendments hereinafter set forth.

## IN THE CLAIMS:

- 13. (Thrice Amended) In a metal etch tool for removing post-RIE polymer rails formed on a Al/Cu metal line of a semiconductor structure, the improvement comprising an integrated metal etch tool comprising therein:
- a) strip chamber means for water only plasma to strip [the] photo-resist [layer] of a semiconductor composite structure [with water only plasma] subsequent to a RIE to limit thickness of sidewall polymer;
  - b) vacuum chamber means to chemically modify